



SDRAM DIMM MODULE, 3.3V 256MByte -32MX64 AVE6432U36A3100E3

FEATURES

INTEL PC100 Version 1.0

- Clock frequency: 100MHz with CAS latency 3
- Burst read/write and burst read/single write capability
- Data input and output masking
- Programmable burst length: 1, 2, 4, 8 and full page
- Programmable burst type: sequential and interleave
- Programmable CAS latency: 3
- Auto refresh and self refresh capability
- 4K refresh per 64ms
- 256 byte serial EEPROM
- LVTTTL-compatible inputs and outputs
- Low active and standby current consumption
- Decoupling capacitors at each memory device
- Double-sided module
- 1.150 inch height
- Gold card edge fingers

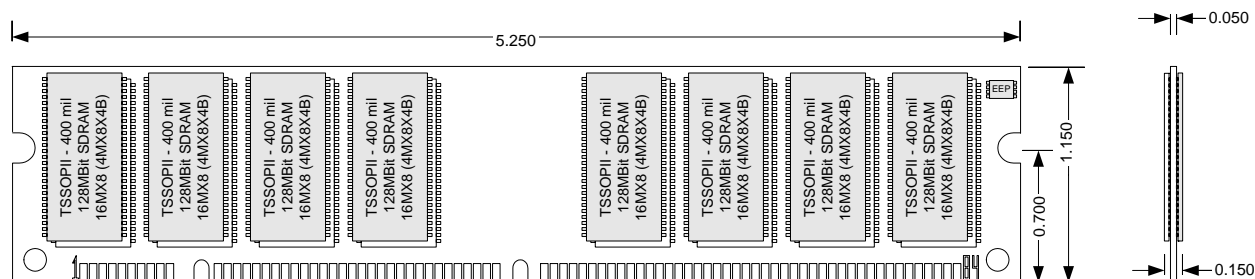
DESCRIPTION

The AVE6432U36A3100E3 is an Unbuffered SDRAM DIMM memory module. This module is based on INTEL PC100 SDRAM DIMM version 1.0. A 256 byte serial EEPROM on board can be used to store module information such as timing, configuration, density, etc.

The AVE6432U36A3100E3 memory module is 256MByte and organized as 32Mx64 array using (16) 16Mx8 (4 internal banks) SDRAMs in TSSOP II packages.

All memory modules are fabricated using the latest technology design, six-layer printed circuit board substrate construction with low ESR decoupling capacitors on-board for high reliability and low noise.

PHYSICAL DIMENSIONS



NOTE: All gray ICs are on the front side of the module, and all white ICs are on the back side of the module

Avant Ordering Guides

AV	E	64	32	U	36	A	3	100	E	3
INVENTORY	MOD. TYPE	ORG.	DENSITY	PARITY	TYPE	VOLT.	FEATURE	SPEED	MODE	REV
AV = AVANT	E = 168-PIN DIMM	64=X64	32=32M	U=UNBUFFERED	36=4Mx8x4 (4K)	A=3.3V	3 = CAS LATENCY 3	100MHz	E=SYNC	REV=3

Other options may be available. Call for specific part number information on options not listed.



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